## **DB3J316N**

## Silicon epitaxial planar type

For small current rectification DB3X316N in SMini3 type package

#### ■ Features

- Short reverse recovery time t<sub>rr</sub>
- Low forward voltage V<sub>F</sub>
- Contributes to miniaturization of sets, reduction of component count.
- Eco-friendly Halogen-free package

## ■ Basic Part Number

Dual DB2S316 (Common cathode)

#### Packaging

Embossed type (Thermo-compression sealing): 3000 pcs / reel (standard)

## ■ Absolute Maximum Ratings $T_a = 25$ °C

Parameter		Symbol	Rating	Unit	
Reverse voltage		$V_R$	30	V	
Repetitive peak reverse voltage	V <sub>RRM</sub>	30	V		
Forward current (Average)	Single	т	100	mA	
	Double	$I_{F(AV)}$	70		
Peak forward current	Single	T	300	mA	
	Double	$I_{FM}$	200		
Non-repetitive peak forward surge current *		I <sub>FSM</sub>	1	A	
Junction temperature		T <sub>j</sub>	125	°C	
Storage temperature		T <sub>stg</sub>	-55 to +125	°C	

Note) \*: 50 Hz sine wave 1 cycle (Non-repetitive peak current)

## ■ Package

Code

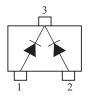
SMini3-F2-B

• Pin Name

1: Anode-1 3: Cathode-1 2: Anode-2 Cathode-2

## ■ Marking Symbol: 5J

#### ■ Internal Connection

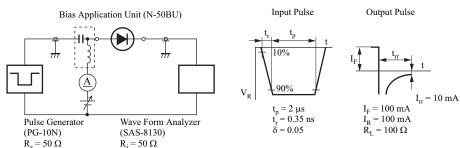


## ■ Electrical Characteristics $T_a = 25$ °C±3°C

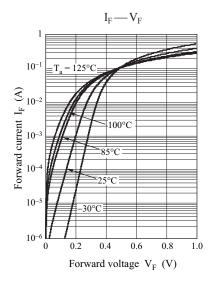
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Forward voltage	V <sub>F</sub>	$I_F = 100 \text{ mA}$			0.55	V
Reverse current	$I_R$	$V_R = 30 \text{ V}$			15	μΑ
Terminal capacitance	C <sub>t</sub>	$V_R = 10 \text{ V}, f = 1 \text{ MHz}$		2		pF
Reverse recovery time *	t <sub>rr</sub>	$I_F = I_R = 100 \text{ mA}, I_{rr} = 10 \text{ mA},$ $R_L = 100 \Omega$		0.8		ns

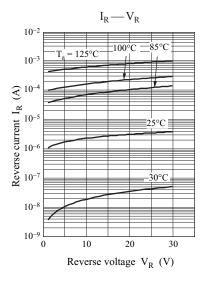
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 measuring methods for diodes.

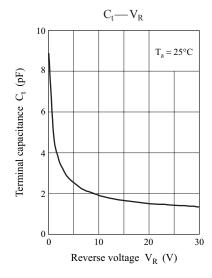
- 2. This product is sensitive to electric shock (static electricity, etc.). Due attention must be paid on the charge of a human body and the leakage of current from the operating equipment.
- 3. Absolute frequency of input and output is 250  $\mbox{MHz}$ 
  - \*: t<sub>rr</sub> measurement circuit



DB3J316N Panasonic



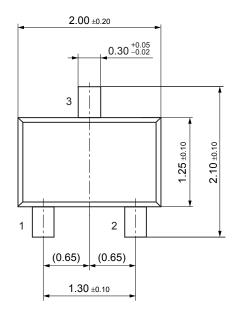


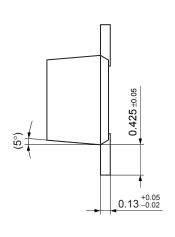


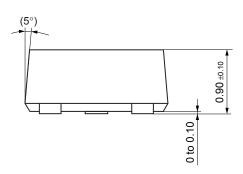
2 Ver. BED

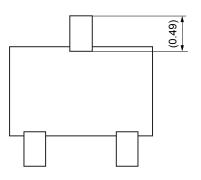
SMini3-F2-B











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